The design, fabrication, and photocatalytic utility of nanostructured semiconductors: focus on TiO$_2$-based nanostructures

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Abstract: Recent advances in basic fabrication techniques of TiO$_2$-based nanomaterials such as nanoparticles, nanowires, nanoplatelets, and both physical- and solution-based techniques have been adopted by various research groups around the world. Our research focus has been mainly on various deposition parameters used for fabricating nanostructured materials, including TiO$_2$-organic/inorganic nanocomposite materials. Technically, TiO$_2$ shows relatively high reactivity under ultraviolet light, the energy of which exceeds the band gap of TiO$_2$. The development of photocatalysts exhibiting high reactivity under visible light allows the main part of the solar spectrum to be used. Visible light-activated TiO$_2$ could be prepared by doping or sensitizing. As far as doping of TiO$_2$ is concerned, in obtaining tailored material with improved properties, metal and nonmetal doping has been performed in the context of improved photoactivity. Nonmetal doping seems to be more promising than metal doping. TiO$_2$ represents an effective photocatalyst for water and air purification and for self-cleaning surfaces. Additionally, it can be used as an antibacterial agent because of its strong oxidation activity and superhydrophilicity. Therefore, applications of TiO$_2$ in terms of photocatalytic activities are discussed here. The basic mechanisms of the photoactivities of TiO$_2$ and nanostructures are considered alongside band structure engineering and surface modification in nanostructured TiO$_2$ in the context of doping. The article reviews the basic structural, optical, and electrical properties of TiO$_2$, followed by detailed fabrication techniques of 0-, 1-, and quasi-2-dimensional TiO$_2$ nanomaterials. Applications and future directions of nanostructured TiO$_2$ are considered in the context of various photoinduced phenomena such as hydrogen production, electricity generation via dye-sensitized solar cells, photokilling and self-cleaning effect, photo-oxidation of organic pollutant, wastewater management, and organic synthesis.

Keywords: TiO$_2$ nanostructure, fabrication techniques, doping in TiO$_2$, TiO$_2$-assisted photoactivity, solar hydrogen, TiO$_2$-based dye-sensitized solar cells, TiO$_2$ self-cleaning, organic synthesis

Introduction

In the last century, scientists have made rapid and significant advances in the field of semiconductor physics. Semiconducting materials have been the subject of great interest due to their numerous practical applications, and they provide fundamental insights into the electronic processes involved. Similarly, material processing has become an increasingly important research field. Many new materials and devices, which possess specific properties for special purposes, have now become available, but material limitations are often the major deterrent to the achievement of new technological advances. Material scientists are now particularly interested in developing materials which maintain their required properties in extreme environments.
After the pioneering works of Efros and Efros\(^1\) and Brus\(^2\) on the size quantization effect in semiconductor nanoparticles, research on nanostructured materials has generated great interest in the scientific community. Tremendous opportunities in science and technology are now possible because of the new properties exhibited by these materials and the challenging problems in theoretical physics associated with the new properties.\(^3\)–\(^6\) In general, ‘nanotechnology’ is the engineering of functional systems at the molecular scale. In its original sense, nanotechnology refers to the projected ability to construct items from the bottom up, using techniques and tools being developed today to make complete, high-performance products. As nanotechnology became an accepted concept, the meaning of the word shifted to encompass the simpler kinds of nanometer-scale technology. Formulation of a road map for development of this kind of nanotechnology is now an objective of a broadly based technology road map project of various leading nanotechnology research groups and institutes in the world. According to the US National Nanotechnology Initiative, the road map of nanotechnology can be divided into four generations (Figure 1). The first era is that of passive nanostructures, which are materials designed to perform one task. The second phase introduces active nanostructures for multitasking; for example, diodes, transistors, actuators, drug-delivery devices, and sensors. We are entering the third generation, which will feature nanosystems with thousands of interacting components. In future, we may expect the development of integrated nanosystems functioning much like a mammalian cell with hierarchical systems within systems.

The optical properties of nanocrystals are related to their size and surface chemistry and drastically differ from those of bulk materials. Preparation and study of high-quality quantum dots, nanobelts, and nanowires have been reported widely.\(^7\)–\(^9\) Achievements in recent years have focused nanomaterials research on the applications in electrical and optoelectronics devices.\(^10\)–\(^12\) Within the class of inorganic materials, oxide-based compounds show the most diverse range of properties. The electronic properties of these materials mainly depend on the nature of cation–oxygen bonding, which is explained either by solid-state band theory or by ionic bonding concepts from solid-state chemistry or by combining aspects of both approaches. This interplay between localized and itinerant character

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**First-generation nanostructures: passive nanosystems~2000**
- Dispersed and contact nanostructures, eg, aerosols and colloids.
- Products incorporating nanostructures, eg, coatings, nanoparticle reinforced nanocomposites, nanostructured metals, nanopolymers, nanoceramics.

**Second-generation nanostructures: active nanosystems~2005**
- Bioactive, health-related, eg, targeted drugs and biodevices.
- Physicochemical active, eg, diodes, transistors, amplifiers, actuators, and adaptive structures

**Third-generation: systems of nanosystems~2010**
- eg, guided assembling, 3-D networking and new hierarchical architectures, robotics, and evolutionary.

**Fourth-generation: molecular nanosystems~2015–2020**
- eg, molecular devices 'by design,' atomic design, and emerging functions.

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**Figure 1** Road map to nanotechnology.
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yields a wide range of electronic properties of metal oxides. For example, a closed-shell compound such as Al₂O₃ is an insulator displaying large band gaps. In many cases, these insulators can serve as effective host materials for efficient luminescence when doped with rare earth or transition metal cations. On the other hand, for closed-shell oxides based on cations with relatively high electronegativity, such as in ZnO and SnO₂, the more covalent nature of bonding yields semiconductors with relatively high carrier mobilities. Electronic oxides containing transition metal cations can yield high conductivity materials, such as SrRuO₃, or even superconductors, as with YBa₂Cu₃O₇. Collective phenomenon involving electric dipole interactions in insulators yields ferroelectrics such as BaTiO₃. Unpaired electron spin in some oxides results in ferromagnetism, as in CrO₂, or ferrimagnetism, as in Fe₂O₃. In addition, many oxides display interesting metal–insulator transitions that are dependent on temperature (eg, V₂O₅), pressure (eg, NiO), or magnetic fields (eg, (La,Sr)MnO₃).13–19 Because of their fundamental properties and obvious utility in applications, significant efforts have been invested in the growth of oxides as epitaxial thin films. Various classes of metal oxides are schematically represented in Figure 2.

Among these oxides, materials scientists are overwhelmingly interested in the fundamental aspects and applications of semiconducting wide-band-gap oxide materials. These types of materials show a wide range of electrical and optical properties. They can be transparent in the visible and infrared (IR) range and can be found in insulators as well as semiconductors. Among these wide-gap oxide materials, we will focus mainly on nanostructured titanium dioxide (TiO₂), also known as titanium (IV) oxide or titania, which is a naturally occurring oxide of titanium. Because of its wide range of applications, from paint to sunscreen to food colorings, and various biological and health-related applications, this technologically important material is the subject of ongoing research and development in design, syntheses, and applications.

Properties of TiO₂
Overview
TiO₂ is a chemically stable, nontoxic, biocompatible, inexpensive material with very high dielectric constant and interesting photocatalytic activities. It is a wide-gap semiconductor, and depending on its chemical composition, it shows a large range of electrical conductivity. In general, TiO₂ has two stable crystalline structures: anatase and rutile.20 Usually, natural rutile crystals are impure, and, therefore, early investigations were limited to ceramic samples only, but later (around 1950s), a colorless, large, single crystal of synthetic rutile was grown by the Boule technique.21–22 Thereafter, most of the research was done on the electro-optical characterization and defect chemistry of rutile single crystals.21–26 Stoichiometry of the rutile TiO₂ is highly dependent on its deposition parameters, especially on annealing conditions and atmosphere.24,27–30 The charge transport phenomenon in rutile is described by small polaron model.31–34 Earlier, it was assumed that the properties of anatase would be similar to those of rutile35 until a new solar cell concept was reported using anatase, which cannot be realized by rutile structure.36 With the possibility of growing synthetic anatase single crystals,37 considerable research to systematically investigate the electronic and optical properties of anatase TiO₂ has begun.35,38–43

In general, titanium metal oxidizes in ambient conditions and a thin layer of native oxide grows on the surface. This surface oxide layer is about 4 nm thick and protects the metal from further oxidation and consists mostly of rutile and anatase TiO₂, but very small amounts of Ti₂O₃ and TiO can also be found.44 This native oxide layer not only passivates the surface, but also resists corrosion from a harsh environment and is useful as an implant material in orthopedic and dental applications.44 TiO₂ powder is commonly used as a pigment in paints, coatings, plastics, papers, inks, fibers, nutrients, toothpaste, and cosmetics.45,46 Due to its high refractive index, it has found important applications in antireflection coatings, narrow-band filters, and optical waveguides.47–52 Often, the properties can be tuned by creating multilayers of TiO₂ and SiO₂.53 in a stacked conformation, where the high refractive index of TiO₂ is combined with the low refractive index of SiO₂ to show interesting optical properties. TiO₂ has also been used as NO₂, oxygen, and hydrocarbon sensors.54–58 The catalytic activities of TiO₂ surface under visible irradiation led to interesting applications in water purification.

![Figure 2 Classifications of metal oxides.](image-url)
(by dissociating pollutants in dissolved organic molecules), water decomposition for hydrogen production,

dye-sensitized solar cells (DSSCs) and electrochromic devices,

solid-state photovoltaic solar cells,

photoelectrochemical anticorrosion coatings, self-cleaning properties,

and superhydrophilicity. Moreover, because it is a highly dielectric material, there are interesting electronic applications for rutile TiO$_2$. Local oxidation of titanium thin films by scanning probe microscopes yields a convenient lithographic patterning technique, which does not require any etching, thus creating microelectronic elements. Silver (Ag)-incorporated TiO$_2$ showed multicolor photochromism under visible irradiation. Some new applications can be possible with this material, such as rewritable color copy paper or high-density multiwavelength optical memories. Rutile is preferred to anatase for optical applications because of its higher refractive index. On the other hand, anatase is preferred for all the applications related to photocatalytic activity, gas sensing, and solar cells, due to its higher mobility and its catalytic properties. Fabrication techniques of doped or undoped TiO$_2$ thin films with a wide variety of properties and morphologies include both wet-chemical and vacuum-based physical techniques. An overview of the available techniques can be found in in the literature. It is noteworthy that the terms ‘TiO$_2$’ and ‘titanium dioxide’ are generally used for slightly substoichiometric films of the composition TiO$_{2-x}$ with $x < 0.1$, which exists in a mixture of rutile, anatase, and amorphous crystalline phases.

**Crystal structure of TiO$_2$**

As mentioned earlier, naturally occurring TiO$_2$ crystal has three common polymorphs: rutile (tetragonal), anatase (tetragonal), and brookite (orthorhombic), along with some less common structures like TiO$_2$ II (columbite), TiO$_2$ III (baddeleyite), TiO$_2$ (H) (hollandite), TiO$_2$ (R) (ramsdellite), and TiO$_2$ (B) (monoclinic) many of which occur only at very particular conditions. Among these structures, rutile is the most stable phase, whereas anatase is metastable at room temperature and transforms irreversibly into rutile upon heating above a threshold temperature around 1000°C (which is in atmospheric conditions, but the threshold temperature can vary from 400°C to 1200°C depending on the grain size, ambient conditions, and impurities). Natural rutile crystals exhibit predominantly (110) surface, which is considered to be the most stable surface of stoichiometric rutile, whereas anatase is the most stable with (101) surface. Figure 3 shows the schematics of the unit cells of the TiO$_2$ crystal structures, and Table 1 shows the unit cell parameters (at room temperature). The rutile unit cell contains two Ti atoms (at [0, 0, 0] and [0, 0, 0, $\frac{1}{2}$, $\frac{1}{2}$, $\frac{1}{2}$]) positions, respectively) and four oxygen atoms (that form a distorted octahedron around Ti). The anatase unit cells contains four Ti atoms (at [0, 0, 0], [0, $\frac{1}{2}$, $\frac{1}{2}$, $\frac{1}{2}$], [0, $\frac{1}{2}$, $\frac{1}{2}$, $\frac{1}{2}$], and [0, $\frac{1}{2}$, 0, $\frac{1}{4}$]) and eight oxygen atoms (that form a distorted TiO$_6$ octahedron around each Ti cation). The TiO$_6$ octahedra constitute the basic building units for the various polymorphic structures of TiO$_2$ and differ from each other by the arrangement and the distortion of the octahedra (Figure 4). In the rutile crystal, each octahedron is connected to two edge-sharing and eight corner-sharing neighboring octahedra, in which the edge-shared octahedra are aligned along the (001) surface direction. In the case of anatase, there are four edge-sharing neighbors, which are aligned along the (100) and (010) surface direction forming zigzag double chains perpendicular to the c-axis, thus creating open channels parallel to the c-axis in rutile and perpendicular to the c-axis in anatase.

Phase diagram of the oxides of titanium shows that by varying the oxygen content from 0 to 2 oxygen per titanium atom, the main phases that can be found at room temperature are Ti, Ti$_2$O, TiO, Ti$_2$O$_3$, Ti$_3$O$_4$, and finally TiO$_2$. Additionally, a series of TiO$_{2n-1}$ (with $n \geq 4$) phases can be found in between Ti$_3$O$_5$ and TiO$_2$ phase, which is called the Magnéli series of homologous compounds, where physical properties are changed dramatically, ranging from metallic...
Table 1 Comparison of the structural, optical, and electrical properties of rutile and anatase

<table>
<thead>
<tr>
<th>Polymorphs</th>
<th>Rutile</th>
<th>Anatase</th>
</tr>
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<tbody>
<tr>
<td></td>
<td>[c]</td>
<td>[\perp c]</td>
</tr>
<tr>
<td>Crystal structure</td>
<td>Tetragonal</td>
<td>Tetragonal</td>
</tr>
<tr>
<td>Space group</td>
<td>$P4_2/mnm$ (136) [84]</td>
<td>$I4_1/amd$ (141) [84]</td>
</tr>
<tr>
<td>Most stable state</td>
<td>(110) [94]</td>
<td>(101) [102]</td>
</tr>
<tr>
<td>Density</td>
<td>4.25 g/cc [84]</td>
<td>3.89 g/cc [84]</td>
</tr>
<tr>
<td>Spectral dependence</td>
<td>$E_1^1$ [35]</td>
<td>$E_1^2$ [35]</td>
</tr>
<tr>
<td>High frequency dielectric constant, $\varepsilon_\infty (\lambda = 600 \text{ nm})$</td>
<td>8.35 [103]</td>
<td>6.76 [103]</td>
</tr>
<tr>
<td>Refractive index</td>
<td>2.89 [103]</td>
<td>2.60 [103]</td>
</tr>
<tr>
<td>Nature of conductivity at room temperature (undoped)</td>
<td>n-Type semiconductor [21,112]</td>
<td></td>
</tr>
<tr>
<td>Mott transition</td>
<td>Not observed [118]</td>
<td>Observed [35]</td>
</tr>
<tr>
<td>Room temperature mobility in crystal</td>
<td>0.1–1 cm$^2$/Vs [22,81]</td>
<td>15 cm$^2$/Vs [35,112]</td>
</tr>
<tr>
<td></td>
<td>0.01 cm$^2$/Vs (high impurity concentration) [81]</td>
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<tr>
<td></td>
<td>$\mu_0 = (2–5) \times \mu_\perp$ [22,476]</td>
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<tr>
<td></td>
<td>0.6–1.5 cm$^2$/Vs [476]</td>
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<tr>
<td>Room temperature mobility in polycrystalline thin film</td>
<td>0.1 cm$^2$/Vs [22,38] CUA</td>
<td>0.1–4 cm$^2$/Vs [35]</td>
</tr>
<tr>
<td>Electron effective mass</td>
<td>9–13 m_e [477]</td>
<td>–1 m_e [35]</td>
</tr>
<tr>
<td></td>
<td>10–30 m_e [22]</td>
<td></td>
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<td></td>
<td>12–32 m_e [26]</td>
<td></td>
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</table>

Figure 4 Arrangement of TiO$_6$ octahedra in relation to the unit cells in A) rutile and B) anatase. Only one chain is shown for each structure. Highlighted bonds are the O–O bonds.

to insulating depending on \( n \). The formation of such reduced oxide phases can be described in terms of the elimination of a plane of oxygen atoms.\(^{30}\) Magnéli phases with \( n \) up to about 38 (\( \text{TiO}_2 \)\(^{97}\))\(^{9}\) and 61 (\( \text{TiO}_1 \)\(^{98}\))\(^{10}\) have been reported, thus creating a very narrow homogeneity range for \( \text{TiO}_2 \) before the lattice tends to break down and the first Magnéli phase appears.\(^{82}\)

**Optical properties of \( \text{TiO}_2 \)**

The dielectric functions of anatase and rutile single crystals for the electric field perpendicular and parallel to the \( c \)-axis (marked with \( \perp \) and \( \parallel \), respectively) show that in the IR to visible spectral range, anatase is less anisotropic than rutile, whereas in the band-gap region, anatase shows important anisotropy.\(^{41,99–105}\) It has been found that depending on the degree of reduction of rutile \( \text{TiO}_2 \), a blue color arises from the visible tail of an IR absorption band peaking at about 0.75–1.18 eV.\(^{22,24,31,99–101}\) Similarly, in anatase too, the blue color has been observed,\(^ {43,102}\) which is caused by a wide absorption band with its maximum in the IR. In addition, a color center at 3 eV due to an oxygen vacancy has been identified giving rise to a yellow color.\(^ {43}\) Various optical parameters of \( \text{TiO}_2 \) can be found in several literatures.\(^ {41,103–106}\)

Table 1 shows various optical properties of \( \text{TiO}_2 \).

**Electrical/electronic properties of \( \text{TiO}_2 \)**

The valence band (VB) of wide-gap rutile and anatase consist of O 2\( p \) states, whereas the conduction band (CB) is formed by Ti 3\( d \) states.\(^ {17,29}\) and detailed calculations on these states can be found in the reports of Tang\(^ {35}\) and Cangiani.\(^ {107}\) Table 1 presents various electrical properties of \( \text{TiO}_2 \), and shows that these properties are dependent on the crystallographic direction. As a wide band-gap semiconductor, \( \text{TiO}_2 \) crystals have a high resistivity (\( \sim 10^{15} \) \( \Omega \)\( \cdot \)cm),\(^ {30}\) and bulk oxygen vacancies, titanium interstitials, and reduced crystal surfaces are considered to generate shallow electron donor levels that contribute to the electric conductivity of \( \text{TiO}_2 \).\(^ {30,108}\) In addition, it has been reported that replacement of oxygen by water vapor remarkably increases the electrical conductivity compared to films deposited with oxygen as reactive gas.\(^ {109}\) Reduced \( \text{TiO}_2 \) is an \( n \)-type semiconductor, and the \( n \)-type conductivity increases with the extent of oxygen loss within the crystal lattice. Point defects in terms of doubly charged oxygen vacancies and interstitial titanium ions with three or four charges affect the conductivity and ionization energy of the rutile crystal.\(^ {28,82}\) The ionization energies have been reported to be around 0.007–0.08 eV (depending on temperature) for titanium interstitials,\(^ {26,110}\) whereas oxygen vacancies contribute to the electronic conduction as double donors with a shallow donor level (0–200 meV) and a deep donor level (600–750 meV).\(^ {22,30,111}\) For anatase, the dominant crystal defects are not yet fully understood: some researchers suggested Ti interstitials caused the dominant defects, whereas others suggested oxygen vacancies for the same, but several reports suggested the existence of both phenomena, with an activation energy of carrier generation around 4 meV.\(^ {30,83,112,113}\) In general, oxygen vacancies are observed to be the dominant phenomenon under weakly reducing conditions or low annealing temperatures (below 870 K in vacuum), whereas in the more reducing conditions and higher annealing temperatures (above 1070 K in vacuum), titanium interstitials become more predominant in effect.\(^ {30,31}\) Enthalpy of oxygen vacancy formation is calculated to be around 4.55 eV/vacancy, whereas the same for the triply charged interstitial titanium atom is around 9.11–9.24 eV/interstitial titanium.\(^ {82,114,115}\) Due to the low value of carrier mobility in rutile \( \text{TiO}_2 \), the transport phenomenon is assumed to follow either small polaron (an electron or hole self-trapped by the local lattice polarization which itself is generating\(^ {16}\) hopping mechanism\(^ {12,116}\) or phonon scattering.\(^ {34}\) Especially, the mobility is shown to decrease in higher temperature, suggesting the presence of large polarons (and not localized small polarons, which may become more mobile at higher temperatures due to thermally activated hopping between the atoms\(^ {35}\)). However, the mobility may decrease if the small polarons diffuse by tunneling,\(^ {13}\) and hence, some interesting charge transport models (such as multiband conduction model\(^ {117}\)) have been proposed for rutile \( \text{TiO}_2 \). On the other hand, the anatase \( \text{TiO}_2 \) shows higher carrier mobility, suggesting Arrhenius-type thermally activated conduction rather than small polaron hopping in rutile.\(^ {35,118}\) However, in both the crystal structures, high concentrations of donors lead to the formation of impurity bands,\(^ {35,118}\) and a transition from nonmetallic to metallic behavior is observed when the donor concentration exceeds a critical value.\(^ {16,119}\)

**Fabrication of nanostructured \( \text{TiO}_2 \)**

With the rapid development of nanotechnology, \( \text{TiO}_2 \) nanostructures in various forms are finding wider applications than before because of their specifically size-related properties. The energy band structure becomes discrete for nanometer-scale \( \text{TiO}_2 \), and its photophysical, photochemical, and surface properties are quite different from those of the bulk ones due to the quantum size effect, and therefore, many works have focused on the synthesis of nanocrystalline \( \text{TiO}_2 \) with a large specific surface area. Syntheses of
0-, 1-, and 2-dimensional nanostructures of TiO$_2$ have been reported widely.

**TiO$_2$ nanoparticles**

TiO$_2$ nanoparticles have specific advantages in the enhancement of light absorption due to the large fraction of surface atoms. Interband electron transition is the primary mechanism of light absorption in pure semiconductors. These transitions are direct as the momentum gain by the electron from light wave is small in comparison with $\hbar / a$ ($a$ is the lattice constant). This absorption is small in direct-forbidden gap semiconductors, as in the case for TiO$_2$, for which the direct electron transitions between the band centers are prohibited by the crystal symmetry. However, momentum is not conserved if the absorption takes place at the boundary of the crystal, for example, at the surface or at the interface between two crystals, which leads to the indirect electron transitions that can result in the essential enhancement of light absorption. This means that considerable enhancement of the absorption can be observed in small nanocrystals where the surface to volume ratio is very high and the fraction of the surface atoms is sufficiently large. The particle size at which the interface enhancement of the absorption becomes significant is around 20 nm. An additional advantage obtained in nanoparticles in the few nanometer size regimes is that the large surface-to-volume ratio makes possible the timely utilization of photogenerated carriers in interfacial processes.

**Vacuum-based physical techniques**

Both vacuum-based and solution-based techniques have been adopted for fabrication of TiO$_2$ nanoparticle. One of the early reported nonsolution techniques is metalorganic chemical vapor deposition (MOCVD). Okuyama and colleagues$^{123-125}$ reported the formation of aerosol particles by gas-phase chemical reaction. They have used titanium tetrakisopropoxide (TTIP) vapor containing ultrafine TiO$_2$ seed particles in a laminar flow aerosol reactor, and the thermal decomposition of TTIP vapor in the controlled cylindrical furnace produced ultrafine TiO$_2$ nanoparticles of size in the range 10–60 nm. They have also studied the effects of the initial concentration of TTIP vapor, the reaction temperature, the temperature profile of the furnace, and properties of seed particles on the particle size distribution to control the nanoparticle formation. Similarly, Ding and colleagues$^{126}$ synthesized TiO$_2$ nanoparticles supported on porous silica gel (60–100 mesh) via MOCVD process, using TTIP as precursor. The chemical vapor deposition (CVD) reactor was a quartz tube with a porous quartz disk at one end. The reactor temperature was controlled by a tubular furnace. TTIP was introduced into the CVD reactor using nitrogen as the carrier gas. The synthesis of TiO$_2$ nanoparticle/silica gel photocatalyst involved three steps: pretreatment of the support materials, CVD reaction, and calcination. On the other hand, Li and colleagues$^{127-129}$ reported the fabrication of transition metal and lanthanide ion (Nd$^{3+}$, Pd$^{2+}$, Pt$^{4+}$, Fe$^{3+}$)-doped TiO$_2$ nanoparticles via MOCVD process using a TTIP precursor. The CVD system is similar to that given in Ding et al,$^{126}$ except for a horizontal reactor. In addition, unlike other works,$^{126}$ this group used Ar-diluted O$_2$ as the carrier plus reactant gas with an elevated reaction temperature for the formation of TiO$_2$ nanoparticles, thus avoiding the additional calcination step. The average particle size reported was 20–25 nm. For doping of TiO$_2$, neodymium (III) acetylacetonate, palladium (II) acetylacetonate, platinum (IV) acetylacetonate, and iron (III) acetylacetonate precursors were used, and the effect of these dopants on the photocatalytic activity of TiO$_2$ nanoparticle is discussed.

Instead of using costly metalorganic precursors, several groups used inorganic materials in conventional CVD system to fabricate silica-supported 10–20 nm TiO$_2$ nanoparticles.$^{130-134}$ Leboda and colleagues reported the CVD syntheses of titania/silica gel$^{130}$ and titania/fumed silica.$^{131}$ In addition, CVD preparations of titania/silica gel and titania/ZSM-5 were also reported by Schrijnemakers and colleagues$^{132}$ and Stakheev and colleagues,$^{133}$ respectively. Xia and colleagues$^{114}$ reported the gas-phase/CVD synthesis of TiO$_2$ nanopowder and investigated the influence of various deposition parameters on particle size. In all these reports, titanium tetrachloride (TiCl$_4$) was applied as the precursor for CVD reaction and a two-step synthesis procedure was used. TiCl$_4$ was first introduced and adsorbed onto the supports, and then oxygen/water vapor was brought through to start the oxidation/hydrolysis of TiCl$_4$ species. Especially, oxidation of TiCl$_4$ vapor, also known as the ‘chloride’ process in titania industry,$^{135-137}$ now becomes one of the main gas-phase routes for commercial production of titania nanopowder. TiCl$_4$ is an inorganic low-cost precursor, which can be readily oxidized or hydrolyzed to prepare TiO$_2$ powders according to the following equations:

\[
\text{TiCl}_4(g) + \text{O}_2(g) \rightarrow \text{TiO}_2(s) + 2\text{Cl}_2(g) \quad (1)
\]

\[
\text{TiCl}_4(g) + 2\text{H}_2\text{O}(g) \rightarrow \text{TiO}_2(s) + 4\text{HCl}(g) \quad (2)
\]

The oxidation method is an important route in a typical gas-phase/CVD method. In gas-phase processes, greater
equilibrium constant ($K_c$) favors the formation of smaller particles, and the $K_p$ value that exceeds $10^{-3}$ is necessary for preparation of nanoscale particles.\textsuperscript{134} Vemury and colleagues\textsuperscript{138} reported the synthesis of TiO$_2$ nanoparticles via oxidation of TiCl$_4$ vapors in electrically assisted hydrocarbon flames using needle-shaped or plate electrodes. A laminar premixed burner-stabilized flame reactor is used to make titania nanoparticles in the presence of externally controlled electric field. TiCl$_4$ vapor premixed with nitrogen, oxygen, and methane were sent through the burner with argon as carrier gas. Oxide particles are formed in the flame by oxidation/hydrolysis of the precursors. External electrodes are used to create the electric field across the flame. In addition, it charged the newly formed particles, resulting in electrostatic repulsion and dispersion, which decreased particle growth by coagulation, thus retaining the nanostructure of synthesized particles. A laser-induced CVD process to prepare TiO$_2$ nanopowders of crystallite size around 20–30 nm has also been attempted by Casey and Haggerty.\textsuperscript{140} Titanium alkoxide vapor was heated with 10.591 μm IR radiation from a CO$_2$ laser. Among other physical techniques, Epperson and colleagues\textsuperscript{141} used an inert gas condensation technique, where the metallic Ti is evaporated in He pressure and then slowly exposed to O$_2$ atmosphere to obtain TiO$_2$ nanoparticles.

Solution-based chemical techniques

Among wet-chemical processes, one of the classical methods was a sulfate process,\textsuperscript{142} where spherical titania nanoparticles were prepared from an aqueous solution of TiOSO$_4$ by homogeneous precipitation using urea at 70°C–90°C. Especially, the presence of urea dictates the spherical shape of the nanoparticles. As-synthesized powders were amorphous hydrates of titania containing a sulfate group and crystallize by calcination into anatase (>500°C) and rutile (>900°C). In calcination, the particles shrink, but hold their original spherical shapes. Other wet-chemical processes include the sol–gel method, which is one of the widely used methods for TiO$_2$ nanoparticle formation,\textsuperscript{143–161} because of its advantage of controlling the particle size and morphology through experimental conditions.\textsuperscript{154} Most of the reports on sol–gel syntheses of TiO$_2$ nanoparticles involved titanium alkoxide (titanium isopropoxide [TIPO], titanium butoxide, titanium ethylhexoxide, tetra-n-butyl titanate) as the Ti source.\textsuperscript{143–146,148–158,160,161} Few used TiCl$_4$ as the Ti precursor solution.\textsuperscript{147,159} The process generally starts with the hydrolysis of the source solution to form the complex sol, followed by heat treatment and aging to obtain the gel, and finally, annealing at elevated temperature to obtain the required oxide. A typical sol–gel synthesis process of TiO$_2$ nanoparticles using TIPO as Ti source is as follows: first, TIPO is mixed with tetra-ethanolamine (TEOA) with TEOA:TIPO = 2:1 ratio, which produces a sol of organometallic complex, and then refluxed and aged under H$_2$O (+HClO$_4$/NaOH) solution for 24 h (at 100°C) to obtain Ti-contained gel, which is subsequently aged for 72 h (at 140°C) to obtain the TiO$_2$ nanoparticle.\textsuperscript{154} Phase-pure anatase nanoparticles are generally prepared from titanium (IV) isopropoxide, TEOA, and/or mild acid-like acetic acid.\textsuperscript{154,162} When stronger acids are used, a fraction of the product usually consists of brookite nanoparticles.\textsuperscript{163,164} The synthesis of brookite nanoparticles has been reported by thermolysis of TiCl$_4$ in aqueous HCl solution.\textsuperscript{165} The composition of the reaction product was found to be strongly dependent on the Ti:Cl concentration ratio (~17–35). Phase-pure rutile nanoparticles have been prepared from TiCl$_4$ or TiCl$_3$ in HCl solution or from titanium (IV) isopropoxide in nitric acid at pH = 0.5.\textsuperscript{166–170} Several authors have compared synthesis methods for the three phases, in order to determine the effect of crystal structure on the physical properties.\textsuperscript{171–174} Reyes-Coronado and colleagues\textsuperscript{174} reported the syntheses of phase-pure anatase, rutile, and brookite TiO$_2$ nanoparticles via a combinatorial approach using both sol–gel and hydrothermal treatment. Amorphous TiO$_2$ nanoparticles were first prepared by sol–gel technique using Ti alkoxide as the source solution followed by hydrothermal treatment at three different acid concentrations and temperatures in order to establish the conditions for obtaining phase-pure products of anatase, rutile, and brookite phases separately. Typically, the hydrothermal condition for the synthesis of anatase phase is reported to consist of heat treatment at 200°C for 6 h under 1.5M acetic acid solution. For obtaining rutile phase, these parameters are 200°C for 8 h under 4M HCl environment, whereas the same for obtaining brookite phase is 175°C for 7 h under 3M HCl solution. Details can be found in the Reyes-Coronado et al.\textsuperscript{174}

Another chemical process used to synthesize TiO$_2$ nanoparticle is hydrothermal synthesis,\textsuperscript{175–177} where TiCl$_4$ was used as the starting materials for Ti source. Rao and Dutta\textsuperscript{178} used Ti alkoxide precursor in toluene solvent to hydrothermally synthesize TiO$_2$ nanoparticle. Palmisano and colleagues\textsuperscript{179} used a coprecipitation method using TiCl$_3$ and aqueous ammonia to form titanium hydroxides followed by firing in air at elevated temperature to obtain TiO$_2$ submicron particles of size 100–300 nm. Akhtar et al.\textsuperscript{180} and Shi et al.\textsuperscript{181} used direct vapor-phase oxidation of TiCl$_4$ in an aerosol.
reactor at elevated temperatures to obtain TiO$_2$ nanoparticles. Jagadale et al.$^{160}$ and Gao et al.$^{182}$ used a wet-chemical peroxide-based synthesis route, where H$_2$TiO$_4$ (or TTIP) dissolved in H$_2$O and/or ammonia solution were used to form peroxotitanate, which was subsequently transformed to TiO$_2$ nanoparticle via low-temperature aging or calcination. Mahshid and colleagues$^{183}$ used peptization method to form TiO$_2$ nanoparticles. Initially, TiO$_2$ colloids in the nanometer range were prepared by hydrolysis and condensation of titanium alkoxide in aqueous media. In the presence of water, alkoxide hydrolyzes and subsequently polymerizes to form a 3-dimensional oxide network. These reactions can be schematically represented as follows:

$$\text{Ti(OR)}_4 + 4\text{H}_2\text{O} \rightarrow 2\text{Ti(OH)}_4$$

$$+ 4\text{ROH} \quad (\text{hydrolysis}), (3a)$$

$$\text{Ti(OH)}_4 \rightarrow \text{TiO}_2 + x\text{H}_2\text{O} + (2 - x)\text{H}_2\text{O}$$

$$\quad \text{(condensation), (3b)}$$

where R is ethyl, i-propyl, n-butyl, etc.$^{184}$ The size, stability, and morphology of the sol produced from alkoxide route is strongly affected by the water-to-Ti molar ratio ($r = [\text{H}_2\text{O}] / [\text{Ti}]$). At $r \approx 10$, spherical, relatively monodisperse particles with diameters of 0.5–1 mm are obtained. On the other hand, at higher $r$ values, the particles formed are unstable and precipitate in the form of large aggregates, which can subsequently be chemically peptized to final sizes that are usually $<100$ nm in diameter. Because of the small size of particles that are formed under these conditions, formation of colloidal TiO$_2$ at high $r$ values is of great interest. In addition, acidity of the solution has a strong influence on the size distribution of nanoparticles.$^{183}$ Li and colleagues$^{185}$ used a solvothermal method to synthesize nanoparticles by controlling the hydrolysis reaction of titanium butoxide using NH$_4$HCO$_3$ and linoleic acid. They have also described the reaction mechanism and formation process of the TiO$_2$ nanoparticles and nanorods by controlling the solvothermal reaction parameters, such as reaction temperatures, concentrations, reaction durations, and so on. Seo et al.$^{186}$ demonstrated the synthesis of TiO$_2$ nanoparticles by a high-temperature nonhydrolytic method using TiCl$_4$, oleic acid, and oleyl amine mixture in a reaction flask at 270°C. After 10 min, the reaction mixture was quenched, and TiO$_2$ nanoparticles were separated by a size-selective precipitation process. Teleki and colleagues$^{187}$ used a flame-based spray pyrolysis method to synthesize TiO$_2$ nanoparticles. TTIP, diluted in a mixture of xylene and acetonitrile, was fed into a combustible spray to obtain the powdered nanoparticles. It is to be noted that for

the physical- or gas-phase processes of TiO$_2$ nanoparticle syntheses, unlike the liquid-phase methods, process parameters can be adjusted easily to produce nanoparticles with varied crystallinity and surface area without the necessity of posttreatments.

### One-dimensional TiO$_2$ nanostructures

One-dimensional nanostructures in the form of nanowires, nanorods, nanotubes, nanopillars, nanocylinders, nanoneedles, and nanowhiskers have received considerable attention because of their potential applications in catalysts as carrier materials, in pharmacy as drug-delivery agents, in nanoelectronics for the isolation of ultrasmall wires, or in basic research to study host–guest chemistry in mesoscopic materials.$^{188-190}$ TiO$_2$-based nanotubes have also attracted wide attention owing to their potential applications in highly efficient photocatalysis,$^{191}$ lithium ion batteries,$^{192}$ photovoltaic cells,$^{193-195}$ and environmental applications.$^{196}$

### Solution-based chemical techniques

Hoyer was the first to attempt to prepare TiO$_2$ nanotubes.$^{197}$ Starting from a porous alumina membrane (PAM), a polymer mold suitable for the formation of TiO$_2$ nanotubes was obtained. The tubular structure was formed by electrochemical deposition in the mold. After dissolution of the polymer, TiO$_2$ nanotubes were obtained, which were amorphous, and transformed into polycrystalline anatase structure after heat treatment. The typical fabrication steps consist of anodic alumina membrane fabrication and gold evaporation on top of the membrane (step 1), followed by casting of poly(methyl methacrylate) (PMMA) within the pores of alumina membrane (step 2). After that the alumina membrane is removed to obtain negative mold (upside down) with evaporated gold inside the replicated pores of PMMA (step 3). Thereafter, electrolless gold deposition on the sidewalls of the PMMA mold is performed (step 4) followed by the electrodeposition of TiO$_2$ on the walls of the mold. Finally, the PMMA mold is removed to obtain free-standing TiO$_2$ nanorods covered with gold layers (step 5).

Kasuga and colleagues$^{198,199}$ synthesized TiO$_2$ nanoneedles (anatase phase) using sol–gel-derived fine TiO$_2$-based powders under hydrothermal NaOH treatment at 110°C for 20 h. Following their pioneering works, several research groups$^{200-219}$ have also synthesized 1-dimensional TiO$_2$ nanostructures by similar chemical processes with some variations in experimental conditions and/or reagents. For example, Feng and colleagues$^{210}$ used tetrabutyl titanate,
titanium tetrachloride in HCl with toluene as the nonpolar solvent to form TiO$_2$ nanowires. Liu and Aydil$^{215}$ used titanium butoxide, TiPO, and titanium tetrachloride as Ti precursors in HCl solution to form nanowires. They also studied the effects of surfactants or salts such as ethylenediamine, ethylenediaminetetraacetic acid, sodium dodecyl sulfate, cetyltrimethylammoniumbromide, polyvinylpyrrolidone, and sodium chloride on the nanowire properties. This group has also used a three-step (hydrothermal + ion exchange + annealing) synthesis of TiO$_2$ nanowires on titanium foil.$^{217}$ In the first step, sodium titanate nanotubes were hydrothermally formed on Ti foil using a NaOH and H$_2$O$_2$ solution. In the second ion-exchange step, the titanium foil with nanotubes was immersed in HCl to exchange the Na$^+$ with H$^+$ and thus transform the sodium titanate nanotubes to hydrogen titanate nanotubes. In the third step, the hydrogen titanate nanotube-coated titanium foil was annealed at 500°C to convert the nanotubes to anatase TiO$_2$ nanowires. Chang and colleagues$^{216}$ used a similar hydrothermal method to the Kasuga group$^{198,199}$ with a microwave oven as the external power source for the reaction. Zhu and colleagues$^{200}$ used sonication-assisted hydrothermal growth of TiO$_2$ nanotubes and nanowhiskers. Wang and colleagues$^{217}$ also used a similar hydrothermal growth of TiO$_2$ nanowires on a spiral-shaped Ti wire. Tian and colleagues$^{219}$ seeded the substrate with TiO$_2$ nanoparticles followed by a similar hydrothermal method.$^{198,199}$ With respect to the formation mechanism of TiO$_2$ nanotubes, Kasuga et al$^{199}$ tentatively proposed that TiO$_2$ nanotubes were grown by the connection between the two ends of Ti–OH forming sheets during the process of washing the alkali-treated TiO$_2$ raw materials. Later Yao and colleagues$^{205}$ explained the nanotube formation mechanism using transmission electron microscopy (TEM) studies. They observed that the TiO$_2$ nanotube walls were not seamless, unlike multiwall carbon nanotubes (CNTs). They argued that crystalline TiO$_2$ raw material underwent delamination in the alkaline solution to produce single-layer TiO$_2$ sheets during alkali treatment. These single-layer TiO$_2$ sheets were later rolled to form TiO$_2$ nanotubes.

Encouraged by these methods, various groups reported the syntheses of 1-dimensional TiO$_2$ nanostructures via porous membrane-based sol–gel and electrochemical routes.$^{196,220-261}$ Use of PAM as the host to grow oriented TiO$_2$ nanowires through the PAM nanopores via sol–gel method has been attempted by several groups.$^{220-237}$ Ti alkoxides have been used as the source solution for the sol–gel syntheses to fill the PAM pores followed by oxygen/air annealing to obtain the TiO$_2$ nanowires. However, this sol–gel template method has some shortcomings. As the only driving force of this technique is capillary action, for the sol with higher concentration, filling of pores is difficult, whereas for low-concentration sol, the as-synthesized nanomaterials lead to shrinkage and cracking.$^{262}$ To overcome these difficulties, Miao and colleagues$^{226}$ reported an electrochemically induced sol–gel method to prepare TiO$_2$ single-crystalline nanowire arrays. For that, one end of the pores are coated with metallic cathode, and an external magnetic field is applied to force the Ti-containing ions to enter into the pores. First, the hydroxyl ion was generated due to the cathodic reduction, and then the generation of OH$^-$ ions increases the local pH at the electrode surface, resulting in the titanium oxyhydroxide gel formation in the pores of the template. Finally, subsequent heat treatment and the removal of the PAM results in the formation of TiO$_2$ single-crystalline nanowire arrays.$^{226}$ Similar methods have been adopted by various others groups.$^{227-230}$ For example, Lin et al$^{227}$ and Zhang et al$^{228}$ used a similar electrochemically induced method to form single-crystalline anatase TiO$_2$ nanowires with diameters about 15 nm and lengths about 6 μm within hexagonally packed nanochannels of porous alumina. They have used acidic TiCl$_4$ as the precursor solution, and using the potentiostatic method with a three-electrode arrangement with a saturated calomel reference electrode (SCE) and a Pt counter electrode, anodic oxidative hydrolysis was done followed by oxygen annealing at 500°C to obtain the desired oxide nanowire arrays. Liu and Huang$^{228}$ used pulsed electrodeposition with acidic TiCl$_4$ as electrolyte solution to grow TiO$_2$ nanowire with PAM.

Caruso et al$^{231}$ used electrospun polymer fibers as host to coat with amorphous TiO$_2$ using a sol–gel technique. On removal of the thermally degradable polymer, hollow titania fibers are produced. The sol–gel coating was able to mimic the finer details of the fiber, thereby forming nodules on the inner walls of the tubes. Similar methods have been adopted by Formo et al$^{232}$ and Archana et al$^{233}$ Jung et al$^{234}$ and Kobayashi et al$^{235}$ demonstrated a new methodology to prepare the TiO$_2$ hollow fibers, double-layered tubular structures, and helical ribbons using a crown-appended cholesterol-based organic gelator in the sol–gel polymerization process of Ti[OCH(CH$_3$)$_2$]$_4$ followed by oxygen annealing at elevated temperature to remove organic components and obtain TiO$_2$ nanostructures. Similarly, Zhang and Qi$^{236}$ used bacterial cellulose membranes as host and followed similar methods stated above to obtain TiO$_2$ nanostructures. Chen and colleagues$^{237}$ synthesized a TiO$_2$ nanowire network on electrospun polymer template using a H$_2$O$_2$, TiOSO$_4$, and KNO$_3$ sol–gel bath.
Anodization of Ti foils and films is one of the most widely used methods for template-free electrochemical deposition of TiO₂ nanowire/nanotube. After the first report of anodic oxidation of Ti film by Zwilling and colleagues,²³⁸,²³⁹ several groups started working on the fabrication of TiO₂ nanowires using the anodization method.¹⁹⁶,²⁴⁰–²⁶¹ HF/NH₄F/KF/NaF/\(\text{(NH}_4\)_2SO_4/NaHSO_4\) diluted in organic solvent or water were taken as the electrolyte in standard two-electrode or three-electrode electrodeposition system with Pt as counter electrode and sample (Ti foil or Ti-coated substrate) as anode (along with a reference electrode for three-electrode system). Highly ordered, oriented hollow nanotubes with very high aspect ratio can be obtained by this method. It should be noted that for aqueous HF/NH₄F used as electrolyte, the length of the nanorods is rather small, which is due to the dissolution of formed TiO₂ under hydrogen ions according to the following reaction process:

\[
\text{TiO}_2 + 6F^- + 4H^+ \rightarrow \text{TiF}_6^{2-} + 2H_2O
\]

(4)

This has been overcome by using nonaqueous organic polar electrolytes²⁵² to decrease the formation of hydrogen ions that are derived from the electrolyte solution, thus reducing the chemical dissolution of formed TiO₂. Using this method, TiO₂ nanotube arrays of ∼1000 µm in length and approximate 10,000 aspect ratio have been achieved.²⁵²

It is also noteworthy that for most of the anodization processes, commercially available Ti foil was used as the source material. Similarly, for PAM-directed growth of the TiO₂ nanowires, the host PAM is fabricated from either Al foil or anodiscs purchased from commercially available sources. Since the as-synthesized nanowires/nanotubes are not supported by any rigid substrate (Si, glass, quartz, and so on), they are fragile and unsuitable for practical device applications. For solid-state device compatibility as well as for some specific device applications in solar cells, field emission studies and sensor applications using vertically standing nanorods supported by rigid substrate are very important.²⁶³–²⁶⁵ Very few groups reported the syntheses of TiO₂ nanowires/rods on rigid substrates.²¹⁰,²³⁷,²⁴⁷,²⁵³ These groups have used indium tin oxide (ITO)/fluorine-doped tin oxide-coated glass/Si substrate with sputter-deposited/evaporated Ti thin films on them as the source materials.

For other chemical-based TiO₂ nanowire syntheses, Venkataramanan and colleagues²⁶⁶ used an environmentally benign approach for the synthesis of titania nanowire using natural fibers (cellulose) as templates and ionic liquid (1-butyl-3-methylimidazolium chloride) as solvent to obtain a TiO₂-nanowire/cellulose composite. Li and Wang²⁶⁷ synthesized rutile TiO₂ nanowhiskers by direct annealing of a precursor powder containing homogeneously mixed NaCl and Ti(OH)₄ particles. Daotong and colleagues²⁶⁸ fabricated single-crystalline TiO₂ nanowires by oxidation of titanium substrates (wire mesh, \(\phi = 0.25\) mm) in the presence of ethanol vapor at a low pressure (10 Torr) and high temperature (450°C). Kim and colleagues²⁶⁹ used a peptide organogel template to fabricate TiO₂ nanonetwork via atomic layer deposition (ALD) process with TTIP and NH₄/H₂O mixed gas as Ti precursor and reactant gas, respectively. Sander and colleagues²⁷⁰ also used ALD to fabricate TiO₂ nanowires within PAM followed by wet etching of the membrane to obtain oriented nanowires. Park and colleagues²⁷¹ used a simple Cu catalyst-assisted thermal annealing process of Ti foil to obtain TiO₂ nanowire and other nanostructures. Wu and Xue²⁷² also used a thermal annealing technique of Ti foil treated with an organic solution containing H₂O₂.

Vacuum-based physical techniques

Among physical techniques for the syntheses of TiO₂ nanowires, various methods have been adopted which include thermal/e-beam evaporation, deposition of Ti and/or TiO₂ in a vacuum evaporator, or RF heating in a controlled atmosphere.²⁷³–²⁸⁰ Xiang et al²⁷³ thermally evaporated Ti powder in a controlled furnace to deposit TiO₂ nanowire on a Si substrate. By controlling the growth conditions such as the reaction time and the position of the substrate, this group has reported the synthesis of SiO₂/TiO₂ shell-core nanostructure.²⁷⁴ Another group²⁷⁵–²⁷⁸ used a two-step thermal evaporation technique, where Ti powder was heated by a radio frequency coil inside a quartz reactor under Ar-diluted O₂ atmosphere to grow TiO₂ nanowires on a Si substrate. On the other hand, Wolcott and colleagues²⁷⁹ used electron-beam evaporation of TiO₂ powder to synthesize nanowires on glass substrates. Other vacuum-based techniques include CVD of TiO₂ nanowhiskers from a system of TiF₄–H₂O at elevated temperatures.²⁸⁰ Francisco and colleagues²⁸¹ used photolithography techniques to fabricate TiO₂ nanowires from thermally annealed TiO₂ thin-film deposited on Si substrate. The fabrication steps consist of TiO₂ thin-film deposition on Si substrate (in fact on a native oxide layer on the Si substrate) followed by spin coating of photoresist and the pattern transfer via masking and UV exposure. After the development, the TiO₂ surface becomes structured with covered photoresist consisting of patterned holes that partially expose the TiO₂ surface underneath via the holes on the photoresist. Finally, a plasma-etching treatment was performed to
etch the exposed parts of the TiO$_2$ layer vertically downward to obtain 1-dimensional nanostructures of TiO$_2$. After the removal of the photoresist, an array of vertically standing TiO$_2$ nanowires on the Si substrate is obtained. Details of the fabrication procedure can be found in Francioso et al.$^{281}$

Lee and colleagues$^{282}$ used vapor–liquid–solid (VLS) growth of TiO$_2$ nanowires on catalyzed (Au) sapphire and quartz substrates using a thermally evaporated Ti powder as source under Ar-diluted O$_2$ as carrier and reactive gases. It is to be noted that the VLS growth technique is a relatively new process, which is mainly used to grow nanowires/rods/whiskers of various elemental and compound materials.$^{283}$ Generally, nanowires of semiconducting materials are conveniently grown via the VLS process, where material from the vapor is incorporated via a liquid catalyst, commonly a low-melting eutectic alloy. Semiconductor nanowires with diameters ranging from a few to several hundred nanometers can be grown on a solid substrate by this method. By modifying the growth conditions, lateral and longitudinal control over the nanowire size, composition, and doping can be achieved. The central idea of the VLS growth technique is the participation of the catalyst during growth process, which is one of the important key factors for the synthesis of nanowires. Another important factor is to keep the catalytic particles in a liquid state during the VLS growth at high temperatures. In general, the VLS growth process can be divided into two stages: the nucleation and the growth of the liquid droplets, and growth of the nanowires from the droplets due to supersaturation by the VLS mechanism. The temperature should be kept high, but the exact temperature will depend on the catalyst used and can be chosen from the phase diagram of the catalytic material, considering the fact that the melting point of nanosized catalytic particles is less than that of bulk material. For example, in VLS growth of TiO$_2$ nanowires, Au catalyst is used at 1050°C.$^{282}$ A VLS apparatus, in general, consists of a tube vacuum furnace with Ar flow through it, an effusion cell to provide the evaporized material (to be grown as nanowires), and the substrate with metallic catalyst on which the required nanowire will be grown. A schematic representation of the system is shown in Figure 5. The diameter of the wires is set by the catalyst dimension (typically 1–100 nm), and the nanowire length (typically 1–100 μm) is proportional to the growth time. During growth, the material to be deposited (here Ti powder) is provided by thermal evaporation of a powder target. The resulting vapor is transported to the substrate in an argon (and oxygen for reactive deposition) flow. The vapor dissolves in the metal particles (Au catalyst) and forms a eutectic mixture. When the liquid particle becomes oversaturated, the crystalline nanowire (TiO$_2$) starts to grow. Because new vapor is supplied continuously, the nanowire will keep on growing and can reach lengths exceeding 100 μm. The growth mechanism is schematically described in Figure 6.

Other TiO$_2$ nanostructures and nanocomposites

Formation of various other nanostructures of TiO$_2$ includes nanoplatelet via hydrothermal/anodization route,$^{255,284}$ porous
Applications of nanostructured TiO$_2$

Fundamentals of TiO$_2$ photoinduced phenomena

After the pioneering report of Fujishima and Honda on the photocatalytic splitting of water on TiO$_2$ electrodes, a new era in the heterogeneous photocatalysis has begun and tremendous research efforts in understanding the fundamental processes and in enhancing the photocatalytic efficiency of TiO$_2$ have been performed by chemists, physicists, materials scientists, chemical engineers, and others. The large oxidizing power of photogenerated holes in titania coupled with the low cost and relative physical and chemical stability of TiO$_2$ render it the semiconductor material of choice for many applications that exploit solar energy including DSSCs where sunlight is converted into electricity, water photoelectrolysis where solar energy is converted into a chemical fuel (hydrogen), photocatalytic conversion of CO$_2$ to hydrocarbon fuels, and as a photocatalyst where organic pollutants are degraded into more environmentally friendly chemical species. All of these applications require TiO$_2$ to be in contact with a solid, liquid, or gaseous electrolyte; consequently, TiO$_2$ becomes a prime candidate for the development of nanoscale architectures. Titania is a wide band-gap semiconductor having an $E_g$-value ranging from 3.0 to 3.2 eV, which depends on the crystalline phase, capable of converting energy from light into chemical redox energy. A photon with energy equal to or higher than that of the band gap transferred an electron from the VB to the CB leaving a hole to VB (cf, enlarged portion of Figure 7). The number of photogenerated electron-hole pairs ($e^-\cdot h^+$) depends on the semiconductor band structure and effective intensity and energy of the incident light. The initial process for heterogeneous photocatalysis of organic and inorganic compounds by semiconductors is this photogeneration of $e^-\cdot h^+$ pairs in the semiconductor particles. Upon excitation, the fate of the separated electron and hole can follow different pathways. Figure 7 illustrates these de-excitation pathways for the electrons and holes.

In the absence of suitable electron or hole scavenger (adsorbed species as charge carrier trapping site), the charge carriers recombine at the surface (cf, path $A/A_1$ of Figure 7) and/or bulk of the semiconductor (cf, path $B$ of Figure 7) to dissipate (heat) energy. On the other hand, when a suitable scavenger is available, the charges migrate to the surface of the TiO$_2$ particle and initiate interfacial redox reaction with the adsorbed species. Thus, TiO$_2$ photosensitizes the reduction of an electron acceptor (A) and the oxidation of an electron donor (D) forming anionic (A$^-$) (cf, path $C_1$ of Figure 7) and cationic (D$^+$) (cf, path...
C2 of Figure 7) species. In nanostructured semiconductors, the surface-to-volume ratio is very high, and hence the reactive surface is also higher in nanomaterial regimes. Therefore, the surface adsorption and interfacial redox reaction can be enhanced by using nanostructured semiconductors.328 This semiconductor-assisted redox reaction is at the core of the heterogeneous photocatalysis. Photocatalysis is generally divided into two classes of processes: 1) when the initial photoexcitation occurs in an adsorbate molecule which then interacts with the ground state catalyst substrate, the process is referred to as a catalyzed photoreaction, and 2) when the initial photoexcitation takes place in the catalyst substrate and the photoexcited catalyst then transfers an electron or energy into a ground state molecule, the process is referred to as a sensitized photoreaction.61 In the subsequent de-excitation processes, which leads to chemical reactions in the heterogeneous photocatalysis process (as mentioned earlier), the electronic population change in the molecular orbitals leads to the different interactions between one reactive center in the excited state and another reactive center in the ground state.

Initially, the donor or acceptor molecules are excited as D → D* or A → A*, where the asterisk represents the excited state. Next, in the electron transfer process, an electron jumps from an occupied orbital of the donor reactant at ground state (D) to the empty orbital of the acceptor reactant at excited state (A*). The electron transfer process requires the overlap between the occupied donor orbital and the empty or half-filled acceptor orbital. The electron transfer results in an ion pair of the donor cation (D+) and the acceptor anion (A−) according to the following equation:

\[
A + D \xrightarrow{\text{TiO}_2} A^- + D^+ \tag{5}
\]

Figure 8A describes the electron transfer from filled ground state donor orbital to half-filled excited acceptor orbital i) or from half-filled excited donor to empty ground state acceptor ii) to form ion pairs (A− + D+). On the other hand, in the energy transfer process, either electron exchange between ground D and excited A* (cf, Figure 8B) or dipole–dipole resonant coupling between ground D and excited A* and vice versa (cf, Figure 8C) are considered to be the responsible
mechanisms for de-excitation of photogenerated e$^-$–h$^+$ pairs. In the electron exchange process, one electron transfers from the ground state-filled D to half-filled A* coupled with simultaneous transfer of another electron from the upper level of half-filled A* to the empty upper level of D. These two processes occur independently in opposite directions and require simultaneous orbital overlap between the interacting centers. On the other hand, dipole–dipole coupling occurs by a Coulombic resonance interaction in which the oscillating dipole of the excited state molecule, D*, is coupled with the induced dipole in a ground state quencher molecule, A. This coupling process does not require effective orbital overlap between the two interacting centers and can operate over a distance of 0.1–10 nm. A detailed discussion of various electron and energy transfer processes can be found in the literature.329–339

The ability of TiO$_2$ to undergo photoinduced electron transfer to adsorbed species on its surface is governed by the band energy positions of the semiconductor and the redox potentials of the adsorbate. Mills and Hunte$^{340}$ discuss band-gap values and the redox (reduction) potential of some oxide and other semiconductor materials with respect to the normal hydrogen electrode (NHE). The CB electron of TiO$_2$ is a moderate reducing agent ($E_{\text{CB}} \sim 0.0$ V vs NHE), whereas the oxidizing power of VB hole is very strong ($E_{\text{VB}} \sim 3.0$ V vs NHE).$^{341}$ Thermodynamically, the redox potentials associated with the CB and VB of TiO$_2$ require the relevant potential level of the acceptor species to be below the CB potential of the TiO$_2$ (ie, more positive), whereas in order to donate an electron to the vacant hole, the potential level of the donor needs to be above the VB position of TiO$_2$ (ie, more negative). Therefore, assuming no kinetic limitations, TiO$_2$-assisted photoinduced interfacial redox reaction will take place with acceptors and donors whose respective reduction potentials are comprised between CB and VB band positions of TiO$_2$.61,341 It is noteworthy that when the TiO$_2$ surface will be under contact with any fluid (gas/liquid) or metal, there will be band bending at the interface due to the redistribution of the charges (and double layer and Schottky barrier formation). For an n-type semiconductor like TiO$_2$, the band bending will be in the upward direction. Due to this redistributed band structure at the surface, e$^-$–h$^+$ recombination process will be affected and, hence, modify the photocatalysis activity of TiO$_2$.

Among anatase and rutile crystal structures of TiO$_2$, anatase shows a higher photocatalytic activity.342 The structure of rutile and anatase are shown in Figures 3 and 4 and described in Table 1. The two crystal structures differ by the distortion of each octahedron and by the assembly pattern of the octahedra chains. These differences in lattice structures cause different mass densities and electronic band structures between the two forms of TiO$_2$ that lead to different photoactivities of these two structures.

**Photolysis on TiO$_2$—solar hydrogen**

Photolysis or photosplitting of water into gaseous O$_2$ and H$_2$ represents one of the most challenging and promising ways of solar energy accumulation, as solar hydrogen can then be used as an alternative fuel. Numerous comprehensive studies$^{343–354}$ have been performed since the first report of photocatalytic water splitting on TiO$_2$ surface was published in 1972.$^{64}$ The band energy position of TiO$_2$ relative to the electrochemical potentials of the H$_2$/H$_2$O and O$_2$/H$_2$O redox couples$^{65,355}$ demonstrates that due to the presence of a large overpotential for the evolution of H$_2$ and O$_2$ on the TiO$_2$ surface, TiO$_2$ alone cannot photodecompose H$_2$O; rather the
photoassisted oxidation of the oxygen vacancy sites on a reduced TiO$_2$ surface is responsible for H$_2$ evolution.$^{61,356}$

TiO$_2$-assisted photoelectrolysis of water is achieved using a close circuit photoelectrochemical cell that consists of a TiO$_2$ anode and a Pt counter electrode and is exposed to near-UV light.$^{64,357}$ Generation of the photoelectrochemical e$^-$–h$^+$ pair in TiO$_2$ is followed by the transfer of electron to the Pt electrode and reduction of water molecule to evolve H$_2$ according to the following reaction:

$$2\text{H}^+ + 2\text{e}^- \rightarrow \text{H}_2,$$

(6a)

whereas at the anode, water oxidation takes place according to following reaction:

$$\text{H}_2\text{O} + 2\text{h}^+ \rightarrow \frac{1}{2}\text{O}_2 \uparrow + 2\text{H}^+.$$  

(6b)

Therefore, the overall photosplitting of water will be given as follows:

$$\text{H}_2\text{O} \xrightarrow[\text{TiO}_2-\text{Pt}]{\text{hv}} \text{H}_2 + \frac{1}{2}\text{O}_2.$$  

(6c)

Sometimes the system requires some external electrical (＞0.25 V) or chemical (alkali in anode half cell and/or acid in cathode half cell) bias to increase efficiency.$^{320-324,340,357}$

In another variation, solar hydrogen is generated by mixing TiO$_2$ powders with noble metals (Pt, Ag, and Au) and oxide (RuO$_2$) particles. Here, this system behaves as a microphotoelectrochemical cell in which the metal (Pt) acts as the cathode and oxide (RuO$_2$) as the anode. Band-gap excitation in the TiO$_2$ injects electrons into the Pt particles and holes into the RuO$_2$ particles. Trapped electrons in Pt reduce water to hydrogen, and trapped holes in RuO$_2$ oxidize water to oxygen.$^{358}$ Various ways of modifying TiO$_2$ particles have been reported, such as metal ion or anion doping, metal ion implantation, dye sensitization, addition of sacrificial or other components to the electrolyte, and so on. However, all these processes produce a very low rate of water splitting.$^{344,346}$ Various measures have been taken to increase the rate of hydrogen evolution over TiO$_2$ surfaces such as using artificial high-power UV light sources and/or nanostructured materials.$^{349}$ However, the energy conversion efficiency on TiO$_2$ was rather low and the reasons for this are 1) fast recombination of photogenerated electrons and holes, 2) fast backward reaction, 3) inability to harvest visible and IR light at longer wavelengths than ～400 nm, and 4) less effective surface area.$^{344}$

### Surface modification of the TiO$_2$ nanostructure

Apart from photosplitting of water, other photochemical activities of TiO$_2$ include adsorption and desorption of O$_2$, CO$_2$, CO, halides, or various organic compounds on nanostructured TiO$_2$ surface$^{359-372}$ and photo-oxidation/reduction of molecular nitrogen, NO$_2$, NH$_3$, CO$_2$, or halides.$^{374-389}$

Photocatalysis being a surface phenomenon, surface area is very important in determining the amount of reaction sites, and charge carriers have to be utilized properly to improve their ability to initiate surface reactions. On the other hand, TiO$_2$ crystallinity should be high to prevent the recombination of e$^-$ and h$^+$. Highly crystalline TiO$_2$ prevents the recombination of charge carriers relative to amorphous and less crystalline TiO$_2$. As mentioned earlier, because the energy conversion efficiency on TiO$_2$ depends on several factors such as surface area, e$^-$–h$^+$ recombination rates, solar energy spectrum, and so on, as a working hypothesis, surface area, and crystallinity of the TiO$_2$ powder have to be improved for efficient photocatalysis.

Modification of the surface area of TiO$_2$ is performed by using nanostructured materials. Nanoparticulate electrodes are commonly used for these purposes, which consist of a several micrometer-thick film consisting of a random 3-dimensional network of interconnected 15–20 nm particles. While these electrodes possess a high surface-to-volume ratio, the structural disorder at the contact between two crystalline electrodes leads to an enhanced scattering of free electrons, thus reducing the electron mobility.$^{390}$ On the other hand, the nanotube array architecture, being ordered and strongly interconnected, eliminates randomization of the grain network and increases contact points for good electrical connection. The nanotube arrays have a large internal surface area and can be easily filled with fluids, thus enabling better close contact with electrolytes. The porosity of the ordered structure allows the incident photons to be more effectively absorbed than on a flat electrode.$^{328}$ Details of the fabrication processes of various nanostructured TiO$_2$ have been discussed previously. Most of these processes used calcination/annealing steps for liquid-phase syntheses or elevated-temperature gas-phase syntheses methods to obtain high crystalline TiO$_2$ nanostructures for improved photocatalytic activities.

### Doping in nanostructured TiO$_2$ for improved photoactivity

Doping of TiO$_2$ nanostructures is another method of improving photoactivities of TiO$_2$. Loading of TiO$_2$ surface with
noble metals and/or metal oxides (RuO₂, ZnO, WO₃, SnO₂) creates low-energy states within TiO₂ that trap photogenerated charge carriers and thus prevent charge recombination which increases the photoactivity of TiO₂. On the other hand, substitutional doping is very important for reducing the band gap of TiO₂ nanostructures to utilize the wider fraction of solar radiation, especially the visible and near infrared (NIR) parts. Much effort has been expended to narrow the TiO₂ band gap by compositional doping. According to the crystal structure of TiO₂, it appears that replacement of Ti⁺⁴ with any cation is relatively easier than to substitute O²⁻ with any other anion due to the difference in the charge states and ionic radii. Cationic doping of TiO₂ with transition and rare earth metals (such as Cu, Zr, Zn, Co, Ni, Cr, Mn, Mo, Nb, V, Fe, Ru, W, Sb, Sn, Au, Ag, Pt, La, Ce, Er, Pr, Gd, Nd, or Sm) has been extensively studied. While several authors have reported that transition metal ion doping decreases the photothreshold energy of TiO₂, there is also an increase in thermal instability and a decrease in carrier lifetimes, which limits overall conversion efficiencies.

For nonmetal doping of TiO₂ in anionic site (oxygen), wide varieties of anionic species (N, S, C, B, P, I, or F) have been used. This approach consists of substitution of a nonmetal atom for oxygen. The methods used to introduce the dopants include wet-chemical, electrochemical, and physical methods, which have been described in detail in the previous sections and related references. Theoretical calculations show that band-gap narrowing originates from the electronic perturbations caused by the change of lattice parameters and/or by the presence of the trap states within conduction and valence bands of TiO₂. Although there is wide consensus that anionic doping produces enhancement in the visible activity of TiO₂ photocatalysts, it is a matter of debate whether this anionic doping is really achieving the necessary band-gap narrowing in TiO₂, to the extent to be really useful in practical applications. Recent studies showed that the visible light activity of TiO₂ can be further enhanced by codoping of suitable combination of metals and/or nonmetal ions, and nonmetal oxides such as CuO, Cu₂O, Fe₂O₃, ZnO, SnO₂, and so on, have been considered for band-gap engineering of TiO₂ as these oxides have compatible processing strategies with TiO₂. Among these oxides, low band-gap CuO or Cu₂O are used as sensitizers to use visible radiation, whereas other large band-gap oxides (eg, ZnO, SnO₂) are coupled with TiO₂ for extrinsic trapping of photogenerated charge carriers to enhance photoactivity. Among these, coupling TiO₂ with SnO₂ attracts much attention. The band gaps of SnO₂ and TiO₂ are 3.88 and 3.2 eV, respectively, and the CB edge of SnO₂ is ~0.5 V above that of TiO₂. When the two semicon ductor particles are coupled, the CB of SnO₂ acts as a sink for photogenerated electrons. Since the photogenerated holes move in the opposite direction, they accumulate in the VB of the TiO₂ particle, which increases the efficiency of charge separation. Recently, a nanocomposite of TiO₂ (anatase)/CNT has been reported to show enhanced photoactivity by reducing charge recombination at TiO₂ surface. It has been observed that single-walled (SW) CNTs can more effectively reduce the charge recombination rate than that of multiwalled (MW) CNTs as the contact area for SWCNT/TiO₂ is much higher than that of MWCNT/TiO₂ (cf, Figure 9A), enhancing photoactivity. Alternatively, metal oxides, such as CuO, Cu₂O, Fe₂O₃, ZnO, MoO₃, ZnO, SnO₂, and so on, have been considered for band-gap engineering of TiO₂ as these oxides have compatible processing strategies with TiO₂. Among these oxides, low band-gap CuO or Cu₂O are used as sensitizers to use visible radiation, whereas other large band-gap oxides (eg, ZnO, SnO₂) are coupled with TiO₂ for extrinsic trapping of photogenerated charge carriers to enhance photoactivity. Among these, coupling TiO₂ with SnO₂ attracts much attention. The band gaps of SnO₂ and TiO₂ are 3.88 and 3.2 eV, respectively, and the CB edge of SnO₂ is ~0.5 V above that of TiO₂. When the two semiconductor particles are coupled, the CB of SnO₂ acts as a sink for photogenerated electrons. Since the photogenerated holes move in the opposite direction, they accumulate in the VB of the TiO₂ particle, which increases the efficiency of charge separation. Recently, a nanocomposite of TiO₂ (anatase)/CNT has been reported to show enhanced photoactivity by reducing charge recombination at TiO₂ surface. It has been observed that single-walled (SW) CNTs can more effectively reduce the charge recombination rate than that of multiwalled (MW) CNTs as the contact area for SWCNT/TiO₂ is much higher than that of MWCNT/TiO₂ (cf, Figure 9A), enhancing

Abbreviations: CNT, carbon nanotubes; MW, multiwall; SW, single wall.

Figure 9 Schematic representation of TiO₂/SWCNT and TiO₂/MWCNT nanocomposite structures. (b) Proposed model for reduction in photogenerated electron-hole recombination in TiO₂/CNT nanocomposites (adapted and redrawn).


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the charge transfer. A simple mechanism has been proposed by Yao and colleagues to qualitatively explain the reduced charge recombination rate in TiO$_2$/CNT nanocomposite (Figure 9B). Physically, the CB edge of TiO$_2$ is $-4.21$ eV lower than vacuum level with a band gap around $3.2$ eV, whereas work function of (SWCNT) is $-4.8$ eV (with respect to vacuum level), with a narrow band gap ranging from $0.0$ to $1.1$ eV. Due to this relative position of CB edges between TiO$_2$ and CNTs, the probability of transfer of the (photogenerated) electrons to the CNTs becomes much higher, leading to a higher lifetime for holes, which consequently enhances its photocatalytic activities.

**TiO$_2$-based DSSCs**

DSSCs have attracted much interest as regenerative low-cost alternatives to conventional solid-state devices due to high energy conversion efficiency and the possibility of large scale production. A DSSC consists of a nanoporous film prepared from nanoparticles of a wide-gap metal oxide (typically TiO$_2$) covered with a monolayer of photosensitizer molecules (a dye, typically ruthenium complexes anchored to the TiO$_2$ surface by a carboxylate bipyridyl ligand) and an electrolyte as a hole transport layer containing redox couples (iodide/tri-iodide). The cell is illuminated through a transparent conducting oxide (TCO) electrode (typically ITO-coated glass) where the semiconductor is deposited. The TiO$_2$ pores are filled with the redox electrolyte which acts as the mediator and establishes electrical contacts with a redox catalyst in the counter electrode. The dyes on the surface of the films absorb light and inject electrons into the CB of the metal oxide. To collect the electrons at a TCO layer, the electrons should travel the distance in the CB from the point where the electrons were injected to the TCO before recombination. A schematic representation of a typical DSSC is shown in Figure 10. Photoexcitation of the dye (sensitizer) is followed by electron injection into the CB of the TiO$_2$ nanostructure. The dye molecule is regenerated by the redox system, which itself is regenerated at the counter electrode by passing electrons through the load. Potentials are referred to the NHE. The open-circuit voltage of the solar cell corresponds to the

![Schematic representation of principle of operation and energy level scheme of the dye-sensitized nanocrystalline solar cell](https://www.dovepress.com/)

**Figure 10** Schematic representation of principle of operation and energy level scheme of the dye-sensitized nanocrystalline solar cell (adapted and redrawn). Luo H, Takata T, Lee Y, Zhao J, Domen K, Yan Y. Photocatalytic activity enhancing for titanium dioxide by co-doping with bromine and chlorine. Chem Mater. 2004;16(5):846–849. Note: The diagram is not drawn to the scale.
difference between the redox potential of the mediator and the Fermi level of the nanocrystalline TiO2 indicated with a dashed line. In the nanoporous TiO2 film, the surface is surrounded by more cations than the electrons, and therefore, it has been assumed that no large electric field gradient is present within the film; hence, the electron transport mechanism is considered to be purely diffusive.452–454

DSSCs differ from solid-state p–n junction for the fact that light absorption and the transport occur separately. The process is described through equations 7a through 7d:

\[
\text{Sensitizer (S) + hv} \rightarrow S^*\text{(excited)} \quad (7a)
\]
\[
S^* + \text{TiO}_2 \rightarrow e^- (\text{TiO}_2) + \text{Oxidized sensitizer}^+ \quad (7b)
\]
\[
\text{Oxidized sensitizer}^+ + \frac{3}{2} I^- \rightarrow S + \frac{1}{2} I_3^- \quad (7c)
\]
\[
\frac{1}{2} I_3^- + e^- (\text{Counter electrode}) \rightarrow \frac{3}{2} I^- \quad (7d)
\]

The light absorption takes place in a monolayer of the photosensitizer (S), which is chemically adsorbed on the surface of TiO2 (Eq. 7a). The photoexcited dye (S*) is then able to transfer electrons into TiO2 (Eq. 7b), which moves toward TCO electrode through the TiO2 porous network. Electrons lost by the sensitizer are recovered using the reduced species present in the electrolyte (I–) (Eq. 7c). Finally, the circuit is closed by the oxidized species of the mediator (I3+) that obtains electrons which flows through the counter electrode through the load (Eq. 7d).

Other photocatalytic applications of nanostructured TiO2

Other photocatalytic activities of TiO2 involve photosensitized oxidation of organic pollutants using TiO2 for environmental remediation, wastewater treatment, recovery of precious metal via TiO2-assisted reduction, organic synthesis,458 photokilling activity,146,356,459,460 or self-cleaning activity.340,356 Photosensitized oxidation of organic pollutants in the aqueous and gaseous phases can be done according to the following reaction:

\[
\text{Organic compound} + O_2 \xrightarrow{\text{hv/TiO}_2 - \text{Pt}} \text{CO}_2 + \text{H}_2\text{O} + \text{Mineral acid} \quad (8)
\]

Similarly, TiO2-assisted organic syntheses comprise 1) oxidation of alkenes substituted with phenyl groups to yield corresponding ketones

\[
\begin{array}{c}
\text{Ph} \\
\text{Ph}
\end{array} \xrightarrow{\text{hv/TiO}_2 - \text{CH}_2\text{CN/O}_2} \begin{array}{c}
\text{Ph} \\
\text{Ph}
\end{array} \xrightarrow{\text{hv}} \begin{array}{c}
\text{Ph} \\
\text{Ph}
\end{array} \xrightarrow{=} \text{O} \quad (9)
\]

2) oxidation of substituted toluene to corresponding acetaldehyde and carboxylic acid, and 3) amine intra-N-alkylation.340 On the other hand, the biggest success of TiO2-based photochemistry is probably the self-cleaning and related phenomena. For example, photoactive TiO2 coated on ceramic or glass undergoes a dual action,440 where on one hand TiO2-assisted photo-oxidation takes place to break down the organic compounds (cf, Eq. 8); on the other hand, simultaneous TiO2-assisted, UV-photoinduced superamphiphilicity (forcing detachment of dust and/or organics) takes place followed by a quick drying process.356,461 Photoinduced superamphiphilicity of TiO2 exhibits high quantum yield at low UV radiation intensities and, therefore, can be exploited efficiently within an indoor setup when illuminated with conventional fluorescent light. Major glass and ceramic manufacturers have already commercialized self-actuating materials based on this superamphiphilicity of TiO2 in automobile and/or bathroom mirrors, or self-cleaning windows/panels.462,463

Conclusions

A comprehensive review of the properties, fabrication, and application of nanostructured TiO2 has been presented in detail, especially the syntheses procedures of 0-, 1-, and quasi-2-dimensional nanostructures of TiO2 via various physical and chemical techniques. Synthesis strategies regarding nanocomposites of TiO2 with other inorganic and organic materials and applications of TiO2 in terms of photocatalytic activities has been reviewed. The basic mechanisms of photoactivities of TiO2 and nanostructures were explored. The characteristics of band-structure engineering and surface modification in nanostructured TiO2 in the context of doping, including elemental and compound materials doping as well as nanocomposite formation with various inorganic/organic materials were discussed. The nanostructured TiO2-assisted photocatalytic energy/fuel generations in terms of solar hydrogen and/or DSSCs have also been discussed in detail. Other photochemical activities of nanostructured TiO2 such as wastewater treatment, organic synthesis, photokilling, and self-cleaning activities have also been discussed briefly. TiO2 nanomaterials are of tremendous interest in a wide range of applications such as photocatalysis, DSSCs, gas sensors, photochromatic devices, photodegradation of organic compounds, deactivation of microorganisms, organic synthesis, and cell culture.
It will not be an exaggeration to say that the next decade will see the renaissance of TiO$_2$-based nanomaterials, and various new, interesting, and novel technological applications are on the verge of exploration.

**Future directions**

In recent years, TiO$_2$-based photocatalytic oxidation of organic compounds has received the most attention, but there is a rapidly increasing focus on the oxidation of volatile organic or inorganic compounds in the gas phase, including NO$_x$ and SO$_x$. Photocatalytic reductions of organic compounds and metal-containing ions and studies on cell killing and disinfection by illuminated TiO$_2$ have also received increasing attention. The current problem with doped TiO$_2$ is the loss of photoactivity during recycling and long-term storage. Future research should be focused on this issue to obtain sustained photocatalytic activity in the long run. Photocatalysis of metal-doped TiO$_2$ under visible light strongly depends on preparation methods. A uniform synthetic strategy is the need of the hour to obtain tailored materials for high-efficient UV-Vis photoreaction. In the case of nonmetal-doped TiO$_2$, the main problem is that its photocatalytic activity under visible light is much lower than that under UV radiation. Therefore, development of new and optimization of the existing photocatalysts exhibiting activity upon visible light with surface characteristics of improved performance and of the high chemical and physical stability are crucial for broader scale utilization of photocatalytic systems in commercial applications. Such materials together with the development of technically applicable self-aligning photocatalytic coating systems adaptable to the major substrates (polymers, glass, ceramics, or metals) will represent a ground-breaking step change in this field, particularly in the economic viability of a range of potential applications. One of the major challenges for the scientific and industrial community involved in photocatalytic research is to increase the spectral sensitivity of TiO$_2$-based photocatalysts to visible and NIR regions. A major area of future research should be the development of new nanostructures of TiO$_2$ with higher surface states, new commercially viable nano-TiO$_2$ fabrication methodology, especially nonlithographic complementary metal–oxide–semiconductor compatible techniques for practical applications, new doping materials, new methods for dopant incorporation into TiO$_2$ nanostructure, as well as new applications for environmental technology. Future research should deal with visible-to-NIR-activated TiO$_2$ functioning in the presence of solar irradiation with predictable photoactivity. Finally, a recent report discusses the photocatalytic cancer-cell treatment using TiO$_2$ nanoparticle, which opens up a very important field in nanobiotechnology for defective cell treatment. Very few groups have studied the biocompatibility of nanostructured TiO$_2$. Since nanostructured TiO$_2$ is extensively used in various applications such as dope, dyes, ceramics, cosmetics, and medicine, where contact with human and/or living cells is necessary, the study of the biocompatibility and biosafety of nano-TiO$_2$ should be considered a very important area of future research.

**Disclosure**

The authors report no conflicts of interest in this work.

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